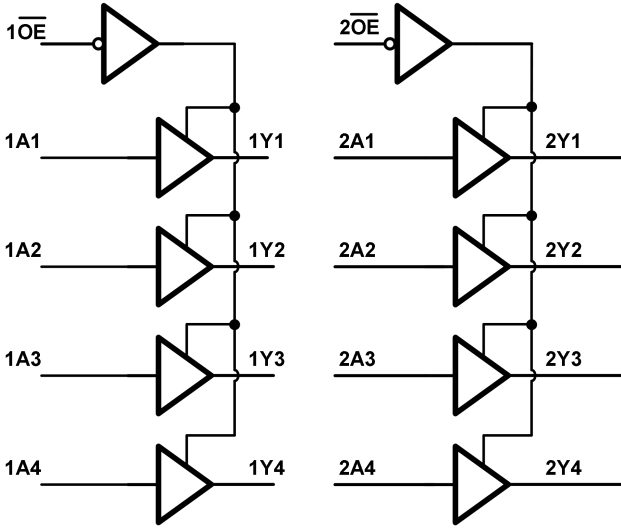


GT74LVC244

Octal Buffer With 3-State Output

1 Features	2 Application
<ul style="list-style-type: none"> - 3-State output - Supports 5 V V_{CC} operation - Inputs accept voltages to 5.5 V - Max t_{pd} of 4.7 ns at 3.3 V - ± 24-mA output drive at 3.3 V - I_{off} supports partial-power-down mode 	<ul style="list-style-type: none"> - Servers - LED displays - Network switches - Telecom infrastructure - Motor drivers - I/O expanders

3 Description	Circuit Diagram
<p>The operating voltage range of the bus buffer gate is 1.65 V to 5.5 V. The GT74LVC244 devices are designed for asynchronous communication between data buses.</p> <p>To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.</p> <p>This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.</p>	

4 Revision History

Revision	Date	Note
Rev. A0. 1	2023. 09. 02	Original Version

The latest datasheet version should be checked on the GTIC official website, as the company does not actively inform customers about updates to the datasheet.

5 Device Summary, Pin and Packages

Table 5-1. Device Summary⁽¹⁾

Serial Name	Part Name	Package	Body Size (Nom)	Marking ⁽²⁾	MSL ⁽³⁾	Package Qty
GT74LVC244	GT74LVC244TG	TSSOP20	6.50mm×4.40mm×1.20mm	GT74LVC244 XXXXXXX	3	Tape and Reel 4000
	GT74LVC244PG	SOP20	12.80mm×7.50mm×2.50mm	GT74LVC244 XXXXXXX	3	Tape and Reel 2000

(1) For all available packages, please contact product sales.

(2) There may be additional marking, which relates to the lot trace code information (data code and vendor code), the logo or the environmental category on the device.

(3) MSL, The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications.

(4) "XXXXX" in Marking will be appeared as the batch code.

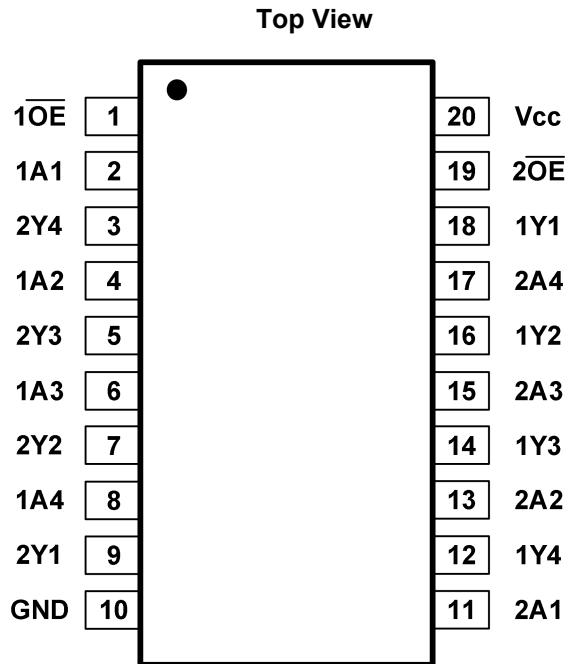
5 Device Summary, Pin and Packages(Continued)


Fig.5-1. GT74LVC244:TG (TSSOP20) Package
 GT74LVC244:PG (SOP20) Package

5 Device Summary, Pin and Packages(Continued)

Table 5-2 TG Pin Definition

Pin		I/O	Description
Name	TG/PG		
$1\overline{OE}$	1	I	Output Enable (Active Low) Pull $1\overline{OE}$ high to place all outputs in 3-state mode.
1A1	2	I	Input
2Y4	3	O	Output
1A2	4	I	Input
2Y3	5	O	Output
1A3	6	I	Input
2Y2	7	O	Output
1A4	8	I	Input
2Y1	9	O	Output
GND	10	—	Ground
2A1	11	I	Input
1Y4	12	O	Output
2A2	13	I	Input
1Y3	14	O	Output
2A3	15	I	Input
1Y2	16	O	Output
2A4	17	I	Input
1Y1	18	O	Output
$2\overline{OE}$	19	I	Output Enable (Active Low) Pull $2\overline{OE}$ high to place all outputs in 3-state mode.
V _{CC}	20	—	Positive Supply

6 Voltage, Temperature, ESD and Thermal Ratings

6.1 Absolute Maximum Ratings⁽¹⁾

Parameters		Min	Max.	Unit
V _{CC}	Supply voltage range	-0.5	6	V
V _I	Input voltage range ⁽²⁾	-0.5	6	V
V _O	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾	-0.5	6	V
V _O	Voltage range applied to any output in the high or low state ⁽²⁾⁽³⁾	-0.5	V _{CC} +0.5	V
I _{IK}	Input clamp current	V _I <0	-50	mA
I _{OK}	Output clamp current	V _O <0	-50	mA
I _O	Continuous output current		±50	mA
	Continuous current through V _{CC} or GND		±100	mA
T _J	Junction temperature under bias		150	°C
T _{stg}	Storage temperature range	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 ESD Ratings

ESD		Value	Unit	
V(ESD)	Electrostatic discharge	Human-Body Model (HBM) ⁽¹⁾	8k	V
		Charged-Device Model (CDM) ⁽²⁾	2k	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6 Voltage, Temperature, ESD and Thermal Ratings(Continued)

6.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

Symbol	Parameter		Min	Max	Unit
V_{CC}	Supply Voltage		1.65	5.5	V
V_I	Input voltage		0	5.5	V
V_O	Output voltage		0	V_{CC}	V
V_{IH}	High-level input voltage	$V_{CC}=1.65V$ to 1.95V	$0.65 \times V_{CC}$		V
		$V_{CC}=2.3V$ to 2.7V	1.7		
		$V_{CC}=3V$ to 3.6V	2		
		$V_{CC}=4.5V$ to 5.5V	$0.7 \times V_{CC}$		
V_{IL}	Low-level input voltage	$V_{CC}=1.65V$ to 1.95V		$0.35 \times V_{CC}$	V
		$V_{CC}=2.3V$ to 2.7V		0.7	
		$V_{CC}=3V$ to 3.6V		0.8	
		$V_{CC}=4.5V$ to 5.5V		$0.3 \times V_{CC}$	
I_{OH}	High-level output current	$V_{CC}=1.65V$		-4	mA
		$V_{CC}=2.3V$		-8	
		$V_{CC}=3V$		-16	
		$V_{CC}=4.5V$		-24	
I_{OL}	Low-level output current	$V_{CC}=1.65V$		4	mA
		$V_{CC}=2.3V$		8	
		$V_{CC}=3V$		16	
		$V_{CC}=4.5V$		24	
T_A	Operating free-air temperature		-40	125	°C

6.4 Thermal Information

Package Type	θ_{JA}	θ_{JC}	Unit
TSSOP20	102.5	35.9	°C/W
SOP20	90.9	55.3	°C/W

7 Electrical Specifications

All typical values are at $V_{CC}=3.3V$, $T_A=+25^{\circ}C$

Parameter	Test conditions	Vcc	-40°C to 85°C			-40°C to 125°C			Unit
			Min	Typ	Min	Typ	Min	Typ	
V _{OH}	I _{OH} =-100 μA	1.65 V to 5.5 V	V _{CC} -0.1			V _{CC} -0.1			V
	I _{OH} =-4 mA	1.65 V	1.2			1.2			
	I _{OH} =-8 mA	2.3 V	1.9			1.9			
	I _{OH} =-16 mA	3 V	2.4			2.4			
	I _{OH} =-24 mA		2.3			2.3			
	I _{OH} =-32 mA	4.5 V	3.8			3.8			
V _{OL}	I _{OL} =100 μA	1.65 V to 5.5 V			0.1			0.1	V
	I _{OL} =4 mA	1.65 V			0.45			0.45	
	I _{OL} =8 mA	2.3 V			0.3			0.3	
	I _{OL} =16 mA	3 V			0.4			0.4	
	I _{OL} =24 mA				0.55			0.55	
	I _{OL} =32 mA	4.5 V			0.55			0.55	
I _i	A or \overline{OE}	V _I =5.5 V or GND	0 to 5.5 V		±5			±5	μA
	Input								
I _{off}	V _I or V _O =5.5 V	0			±10			±10	μA
I _{oz}	V _O =0 to 5.5 V	3.6 V			10			10	μA
I _{cc}	V _I =5.5 V or GND, I _O =0	1.65 V to 5.5 V			10			10	μA
ΔI _{cc}	One Input at V _{CC} -0.6 V, Other Inputs at V _{CC} or GND	3 V to 5.5 V			500			500	μA
C _i	V _I =V _{CC} or GND	3.3 V		5				5	pF

(1) All unused digital inputs of the device must be held at V_{IO} or GND to ensure proper device operation.

7 Electrical Specifications(Continued)

Typical Values at $T_A=+25^\circ\text{C}$ and nominal voltages 1.8V, 2.5V, 3.3V, and 5.0V.

Parameter	From (Input)	To (Output)	-40°C to 125°C								Unit
			$V_{CC}=1.8\text{ V} \pm 0.15\text{ V}$		$V_{CC}=2.5\text{ V} \pm 0.15\text{ V}$		$V_{CC}=3.3\text{ V} \pm 0.15\text{ V}$		$V_{CC}=5\text{ V} \pm 0.15\text{ V}$		
			Min	Max	Min	Max	Min	Max	Min	Max	
t_{pd}	A	Y	2.8	9.5	1.2	5.8	1	4.7	1	3.2	ns
t_{en}	$\overline{\text{OE}}$	Y	3.3	10.8	1.5	6.9	1	5.6	1	5.2	ns
t_{dis}	$\overline{\text{OE}}$	Y	1.3	11.8	1	5.2	1	5.2	1	4.4	ns

$T_A=25^\circ\text{C}$

Parameter		Test Conditions	$V_{CC}=1.8\text{ V}$	$V_{CC}=2.5\text{ V}$	$V_{CC}=3.3\text{ V}$	$V_{CC}=5\text{ V}$	Unit
			Typ	Typ	Typ	Typ	
C_{pd}	Power Dissipation Capacitance	f=10 MHz	17	18	25	30	pF

8 Typical Characteristics

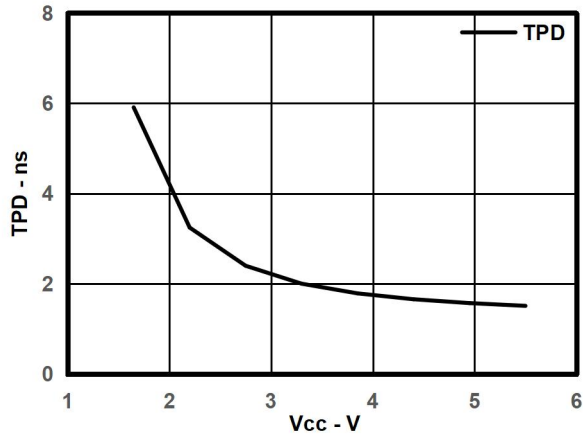


Fig.8-1. Typical Tpd vs Vcc

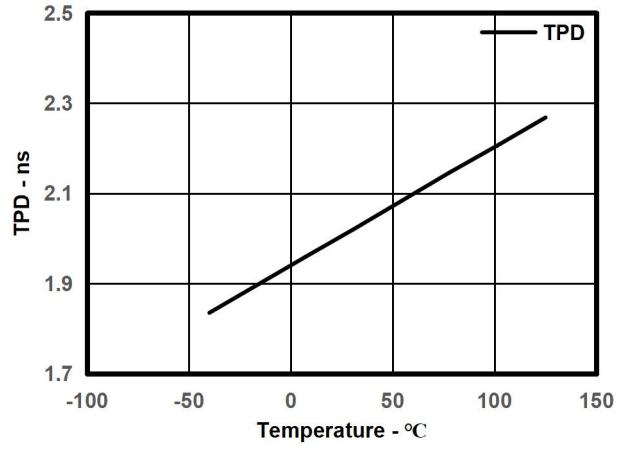
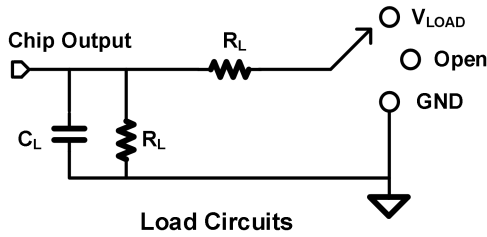


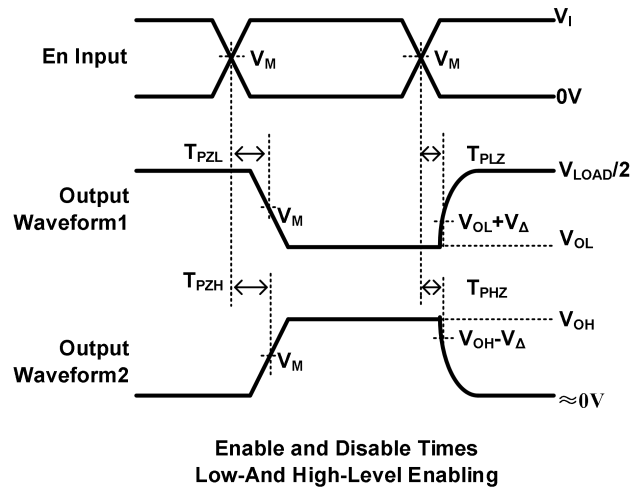
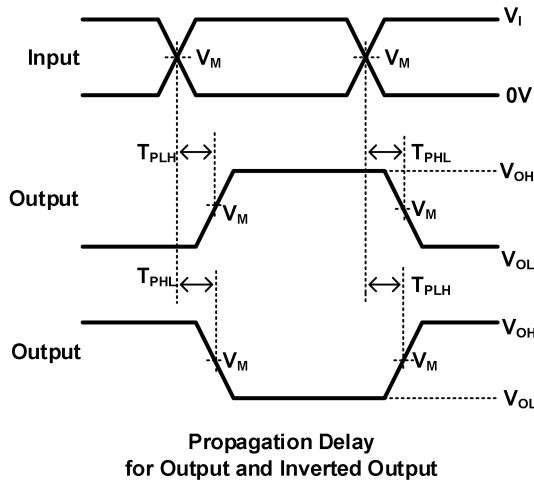
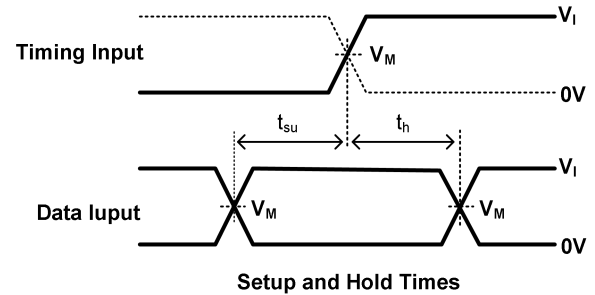
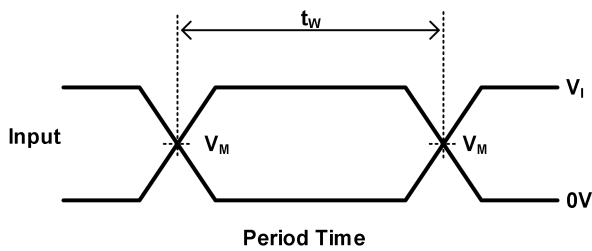
Fig.8-2. Typical Tpd vs Temp

9 Measurement Information



TEST	S1
T_{PHL}/T_{PLH}	OPEN
T_{PLZ}/T_{PZL}	V_{LOAD}
T_{PHZ}/T_{PZH}	GND

V_{CC}	Inputs		V_M	V_{LOAD}	C_L	R_L	V_{Δ}
	V_i	T_r/T_f					
$1.8V \pm 0.15V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	30pF	1k Ω	0.15V
$2.5V \pm 0.15V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	30pF	500 Ω	0.15V
$3.3V \pm 0.15V$	3V	$\leq 2.5ns$	1.5V	6V	50pF	500 Ω	0.3V
$5V \pm 0.15V$	V_{CC}	$\leq 2.5ns$	$V_{CC}/2$	$2 \times V_{CC}$	50pF	500 Ω	0.3V



Notes: A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: PRR 10 MHz, $Z = 50\Omega$.

D. The outputs are measured one at a time, with one transition per measurement.

E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .

F. t_{PZL} and t_{PZH} are the same as t_{en} .

G. t_{PLH} and t_{PHL} are the same as t_{pd} .

H. All parameters and waveforms are not applicable to all devices.

10 Detailed Description

10.1 Overview

The GT74LVC244 device is organized as two 4-bit buffers/line drivers with separate output-enable (\overline{OE}) inputs. The device passes data from the A inputs to the Y outputs when \overline{OE} is low. The outputs are in the high-impedance state when \overline{OE} is high. \overline{OE} should be tied to V_{CC} through a pullup resistor to ensure the high-impedance state during power up or power down; the minimum value of the resistor is determined by the current-sinking capability of the driver.

10.2 Functional Block Diagram

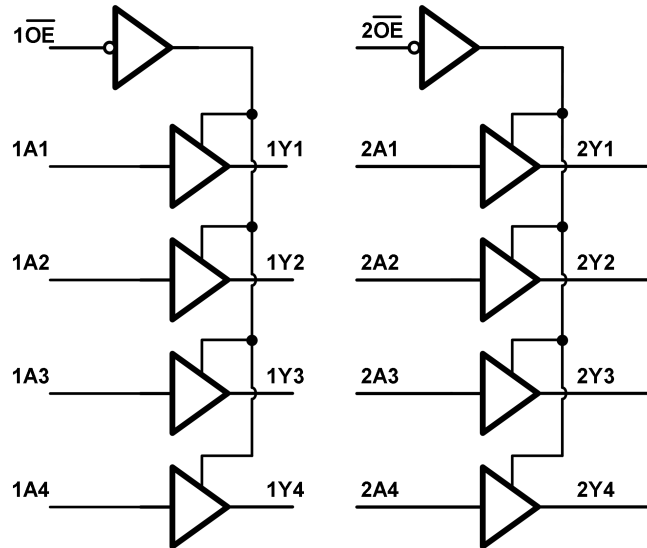


Fig.10-1

10.3 Feature Description

The GT74LVC244 have wide operating voltage range from 1.65 V to 5.5 V, It Allows down voltage translation and I_{off} feature allows voltages on the inputs and outputs, when V_{CC} is 0 V.

10.4 Device Functional Modes

Table 10-1 Function Table

Inputs		Output
\overline{OE}	A	Y
L	H	H
L	L	L
H	X	Z

11 Application Note

11.1 Application Information

GT74LVC244 is a high drive CMOS device that can be used for a multitude of bus interface type applications where output drive or PCB trace length is a concern. The inputs can accept voltages to 5.5 V at any valid V_{CC} making it ideal for down translation.

11.2 Typical Application

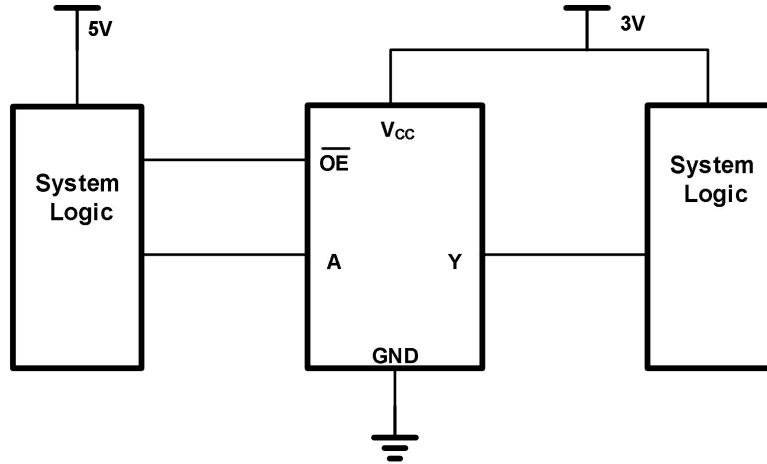
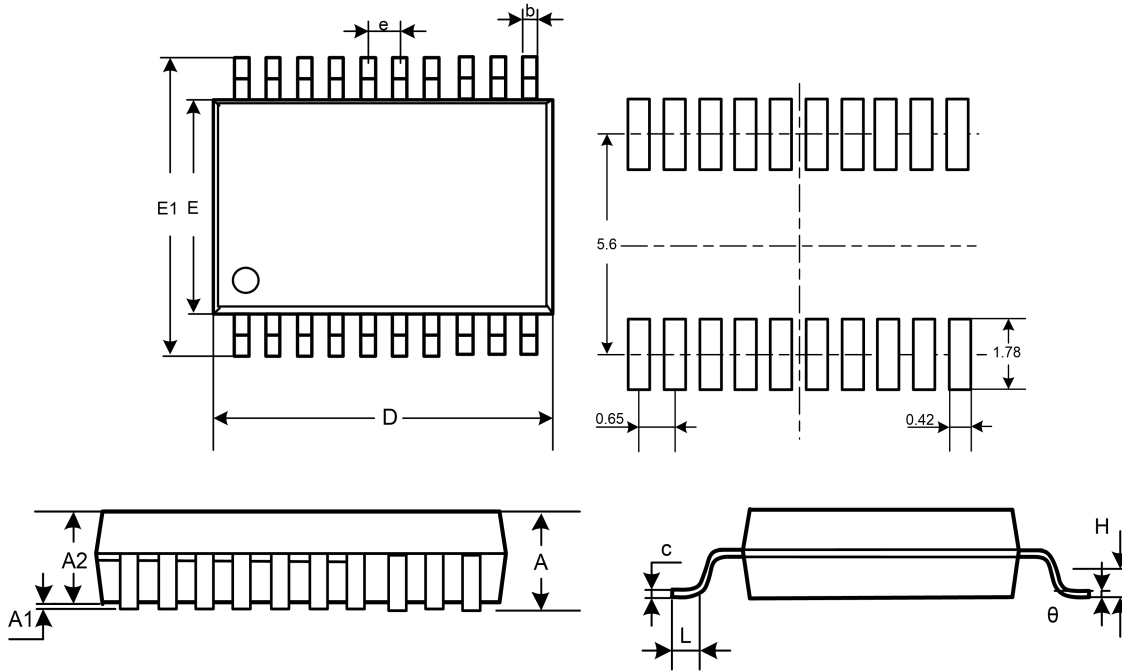


Fig. 11-1

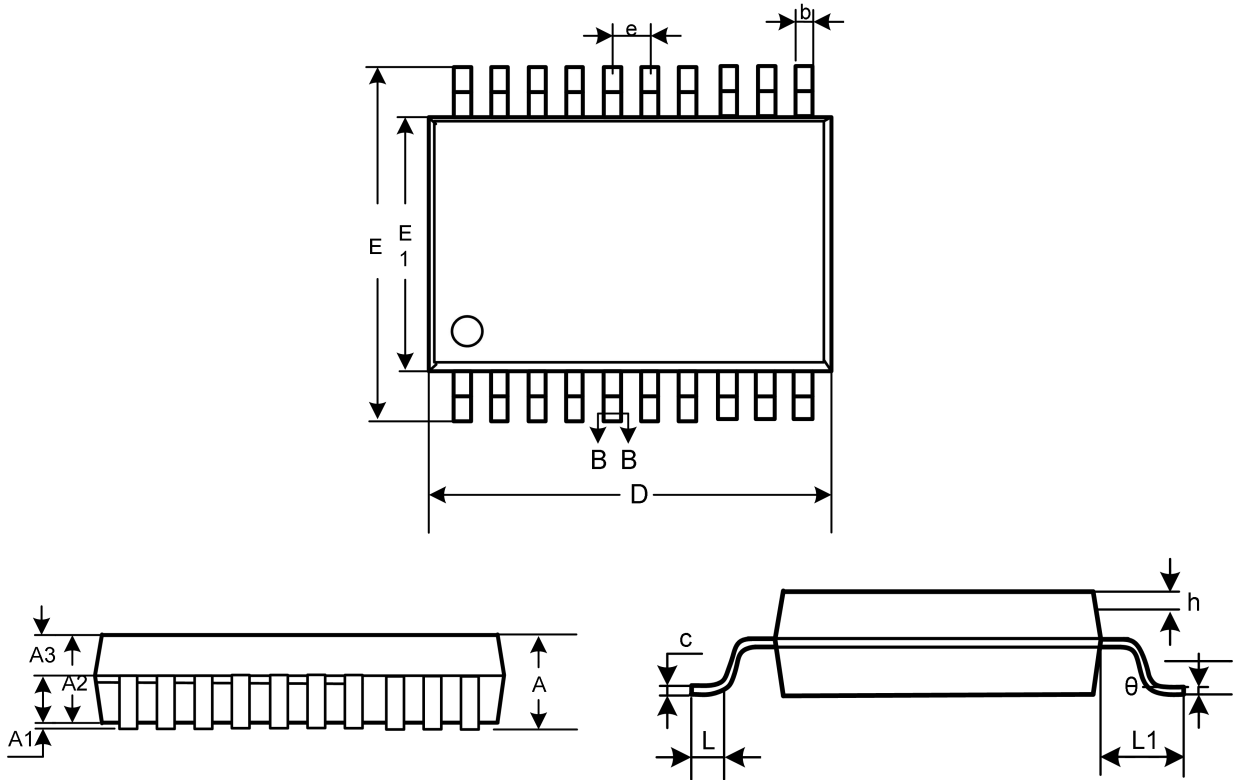
12 Package Outline Dimension

TSSOP20


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.200	0.280	0.008	0.011
c	0.130	0.170	0.005	0.007
D	6.400	6.600	0.252	0.260
E	4.300	4.500	0.169	0.177
E1	6.200	6.600	0.244	0.260
e	0.650BSC		0.026BSC	
L	0.450	0.750	0.018	0.030
H	0.250TYP		0.010TYP	
θ	0°	8°	0°	8°

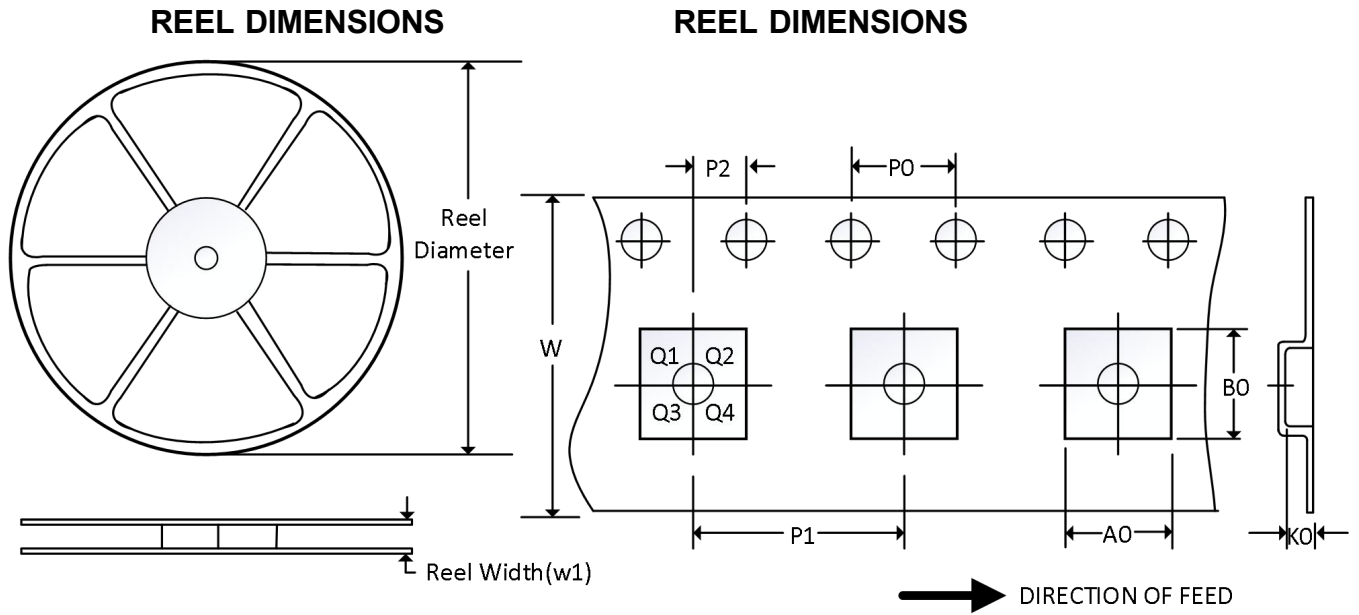
12 Package Outline Dimension (Continued)

SOP20



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	--	2.65		0.104
A1	0.10	0.30	0.004	0.012
A2	2.25	2.35	0.089	0.093
A3	0.97	1.07	0.038	0.042
b	0.39	0.47	0.015	0.018
c	0.25	0.29	0.010	0.011
D	12.70	12.90	0.500	0.508
E	10.10	10.50	0.398	0.413
E1	7.40	7.60	0.291	0.299
e	1.27BSC		4.17BSC	
L	0.70	1.00	0.028	0.039
L1	1.40REF		4.59REF	
theta	0°	8°	0°	8°
h	0.50REF		1.64REF	

13 TAPE AND REEL INFORMATION



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width(mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TSSOP20	13"	12.4	6.75	6.95	1.2	4	8	2	16	Q1
SOP20	13"	24.4	10.75	13.55	2.65	4	12	2	24	Q1

NOTE:

1. All dimensions are nominal.
2. Plastic or metal protrusions of 0.15mm maximum per side are not included.